

Electrical Specifications

65548 ABSOLUTE MAXIMUM CONDITIONS

Symbol	Parameter	Min	Typ	Max	Units
P_D	Power Dissipation	—	—	1.8	W
V_{CC}	Supply Voltage	−0.5	—	7.0	V
V_I	Input Voltage	−0.5	—	$V_{CC}+0.5$	V
V_O	Output Voltage	−0.5	—	$V_{CC}+0.5$	V
T_{STG}	Storage Temperature	−40	—	125	° C

Note: Permanent device damage may occur if Absolute Maximum Ratings are exceeded.
Functional operation should be restricted to the conditions described under Normal Operating Conditions.

65548 NORMAL OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Units
V_{CC}	Supply Voltage (for 5V operation)	4.5	5	5.5	V
V_{CC}	Supply Voltage (for 3.3V operation)	3.1	3.3	3.6	V
T_A	Ambient Temperature	0	—	70	° C

65548 DAC CHARACTERISTICS

(Under Normal Operating Conditions Unless Noted Otherwise)

Symbol	Parameter	Notes	Min	Typ	Max	Units
V_O	Output Voltage	$I_O \leq 10 \text{ mA}$	1.5	—	—	V
I_O	Output Current	$V_O \leq 1 \text{ V @ } 37.5 \Omega \text{ Load}$	21	—	—	mA
	Full Scale Error		—	—	± 5	%
	DAC to DAC Correlation		—	1.27	—	%
	DAC Linearity		± 2	—	—	LSB
	Full Scale Settling Time		—	—	28	nS
	Rise Time	10% to 90%	—	—	6	nS
	Glitch Energy		—	—	200	pVsec
	Comparator Sensitivity		—	50	—	mV

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65548 DC CHARACTERISTICS

(Under Normal Operating Conditions Unless Noted Otherwise)

Symbol	Parameter	Notes	Min	Typ	Max	Units
I _{CCE5}	Power Supply Current	0° C, 5.5V, MCLK=75 MHz, DAC on ††	–	TBD	TBD	mA
I _{CCO5}	Power Supply Current	0° C, 5.5V, MCLK=75 MHz, DAC off ††	–	TBD	TBD	mA
I _{CCE3}	Power Supply Current	0° C, 3.3V, MCLK=75 MHz, DAC on ††	–	TBD	TBD	mA
I _{CCO3}	Power Supply Current	0° C, 3.3V, MCLK=75 MHz, DAC off ††	–	TBD	TBD	mA
I _{CCSD}	Power Supply Current	0° C, 3.3V, Standby, SelfRefresh DRAMs†	–	TBD	TBD	μA
I _{CCSS}	Power Supply Current	0° C, 3.3V, Standby, SlowRfsh 32KHZ in	–	TBD	TBD	μA
I _{CCSR}	Power Supply Current	0° C, 3.3V, Standby, SlowRfsh XTALI in	–	TBD	TBD	μA
I _{IL}	Input Leakage Current		–100	–	+100	uA
I _{OZ}	Output Leakage Current	High Impedance	–100	–	+100	uA
V _{IL}	Input Low Voltage	All input pins	–0.5	–	0.8	V
V _{IH}	Input High Voltage	All input pins	2.0	–	V _{CC} +0.5	V
V _{THR}	Input Switch Point	All inputs except RESET# & STNDBY#	–	1.4	–	V
V _{HYS}	Input Hysteresis	RESET# and STNDBY#	–	± 0.15	–	V
V _{OL5}	Output Low Voltage	Under max load per table below (5V)	–	–	0.5	V
V _{OL3}	Output Low Voltage	Under max load per table below (3.3V)	–	–	0.5	V
V _{OH5}	Output High Voltage	Under max load per table below (5V)	2.4	–	–	V
V _{OH3}	Output High Voltage	Under max load per table below (3.3V)	0.7 x V _{CC}	–	–	V

65548 DC DRIVE CHARACTERISTICS

(Under Normal Operating Conditions Unless Noted Otherwise)

Symbol	Parameter	Output Pins	DC Test Conditions	Min	Units
I _{OL}	Output Low Drive	H/VSYN, LDEV#, LRDY#, ROMCS#	V _{OUT} =V _{OL} , see note†††	12	mA
		FLM, LP, M, P0-15, SHFCLK, D0-31	V _{OUT} =V _{OL} , see note†††	8	mA
		ENAVEE, ENAVDD, ENABKL, ACTI	V _{OUT} =V _{OL} , see note†††	8	mA
		RASA#, CASAH/L#, WEA#, PAR, BLANK#	V _{OUT} =V _{OL} , see note†††	4	mA
		RASB#, CASBH/L#, WEB#, OEAB#, AA0-9	V _{OUT} =V _{OL} , see note†††	4	mA
		RASC#, CASCH/L#, WEC#, OEC#, CA0-8	V _{OUT} =V _{OL} , see note†††	4	mA
		All other outputs	V _{OUT} =V _{OL} , see note†††	2	mA
I _{OH}	Output High Drive	H/VSYN, LDEV#, LRDY#, ROMCS#	V _{OUT} =V _{OH} , see note†††	12	mA
		FLM, LP, M, P0-15, SHFCLK, D0-31	V _{OUT} =V _{OH} , see note†††	8	mA
		ENAVEE, ENAVDD, ENABKL, ACTI	V _{OUT} =V _{OH} , see note†††	8	mA
		RASA#, CASAH/L#, WEA#, PAR, BLANK#	V _{OUT} =V _{OH} , see note†††	4	mA
		RASB#, CASBH/L#, WEB#, OEAB#, AA0-9	V _{OUT} =V _{OH} , see note†††	4	mA
		RASC#, CASCH/L#, WEC#, OEC#, CA0-8	V _{OUT} =V _{OH} , see note†††	4	mA
		All other outputs	V _{OUT} =V _{OH} , see note†††	2	mA

Note: †Measured with all chip inputs driven to inactive levels and outputs not connected (or connected to typical external loads).

Note: ††640x480x8bpp, TFT panel (for power data for other configurations, contact Chips and Technologies in San Jose, California)

Note: †††IOL & IOH drive listed above indicates 5V low drive (V_{CC}=4.5V) and 3.3V high drive (V_{CC}=3V), as programmed via XR6C bits 2-5.

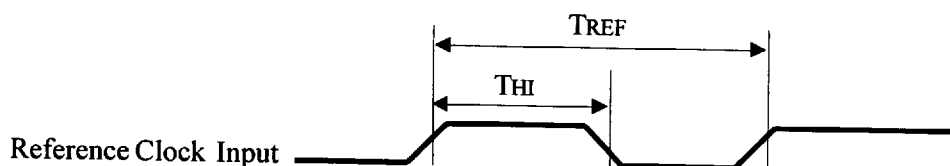
Note: Unless otherwise specified, specifications above apply to both 5V & 3.3V operation & memory clock is assumed to be 75MHz. Electrical specifications contained herein are preliminary and subject to change without notice.

65548 OUTPUT DRIVE CAPACITY

Note: Please refer to Pin List section for the drive capacity and maximum output load of individual pins.
See pages 27-31.

65548 AC TIMING CHARACTERISTICS - REFERENCE CLOCK

Symbol	Parameter	Notes	Min	Typ	Max	Units
T_{REF}	Reference Frequency	(± 100 ppm)	—	14.31818	—	MHz
T_{REF}	Reference Clock Period	$1/F_{REF}$	—	69.84128	—	nS
T_{HI}/T_{REF}	Reference Clock Duty Cycle		25	—	75	%

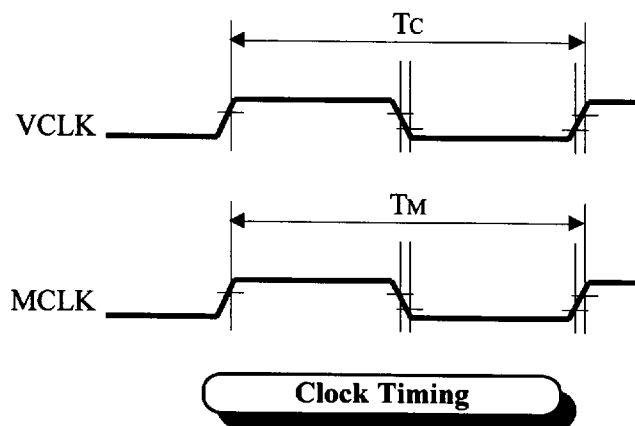


Reference Clock Timing

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65548 AC TIMING CHARACTERISTICS - CLOCK GENERATOR

Symbol	Parameter	Notes	Min	Typ	Max	Units
T_C	VCLK Period (5V)	80 MHz	12.5	—	—	nS
T_C	VCLK Period (3.3V)	80 MHz	12.5	—	—	nS
T_M	MCLK Period (5V)	75 MHz	13.33	—	—	nS
T_M	MCLK Period (3.3V)	75 MHz	13.33	—	—	nS



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65548 AC TIMING CHARACTERISTICS - RESET

Symbol	Parameter	Notes	Min	Max	Units
T_{IPR}	Reset Active Time from Power Stable	See Note 1	5	—	mS
T_{ORS}	Reset Active Time from Ext. Osc. Stable	See Note 2	—	—	—
T_{RES}	Reset Active Time with Power Stable	See Note 3	2	—	mS
T_{STR}	Reset Active Time from Standby	See Note 4	2	—	mS
T_{RSR}	Reset Rise Time	Reset fall time is non-critical	—	20	nS
T_{RSO}	Reset Active to Output Float Delay		—	40	nS
T_{CSU}	Configuration Setup Time	See Note 5	20	—	nS
T_{CHD}	Configuration Hold Time		5	—	nS

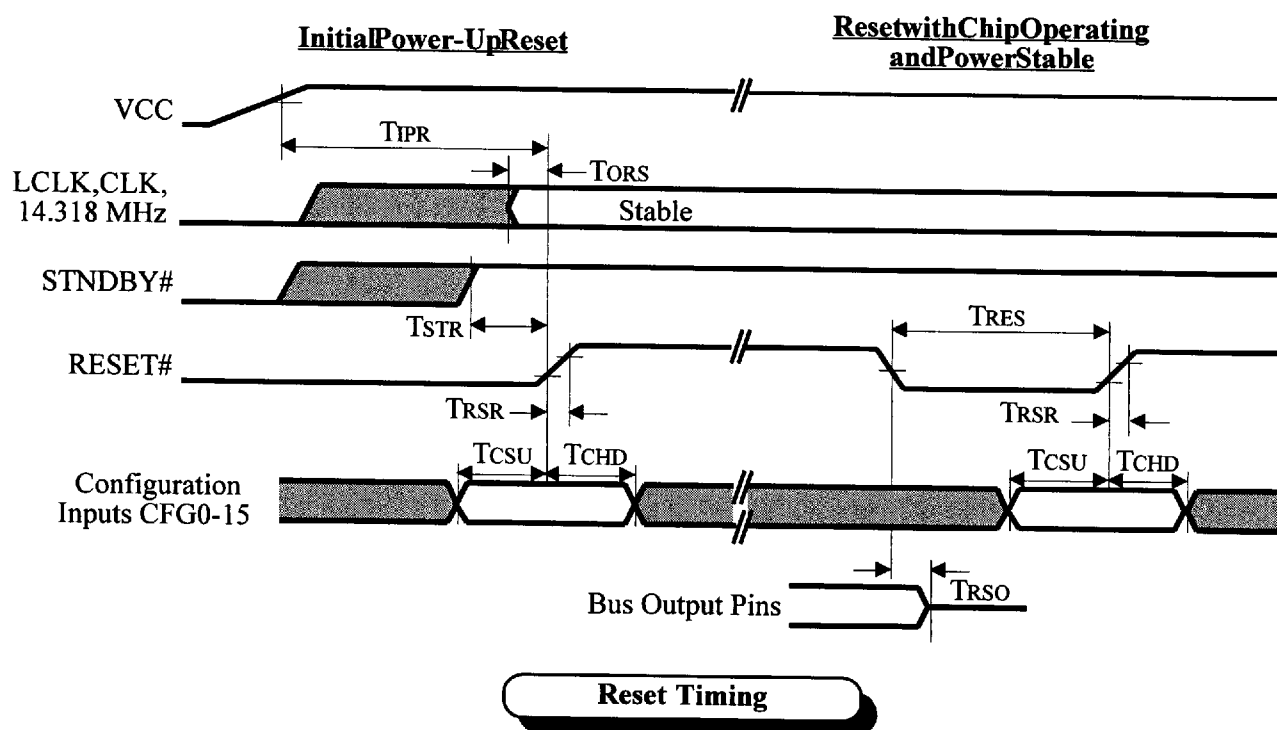
Note 1: This parameter includes time for internal voltage stabilization of all sections of the chip, startup and stabilization of the internal clock synthesizer, and setting of all internal logic to a known state.

Note 2: The external oscillator input is required. LCLK in Local Bus and CLK in PCI Bus modes should have the normal operating frequency during reset. The 65548 should see a minimum of 10 clocks before the inactive edge of Reset#.

Note 3: This parameter includes time for the internal clock synthesizer to reset to its default frequency and time to set all internal logic to a known state. It assumes power is stable and the internal clock synthesizer is already operating at some stable frequency.

Note 4: STNDBY# pin must be high when RESET occurs to properly reset the chip. On the other hand, RESET# can be pulled low during Standby mode without affecting Standby mode.

Note 5: Setup time to latch the state of the configuration bits reliably into XR01, XR6C, and XR74 is specified by this parameter. Changes in some configuration bits may take longer to stabilize inside the chip (such as internal clock synthesizer-related bits 4 and 5). It is therefore recommended that configuration bit setup time be T_{RES} (2mS) to insure that the chip is in a completely stable state when Reset goes inactive.


Reset Timing

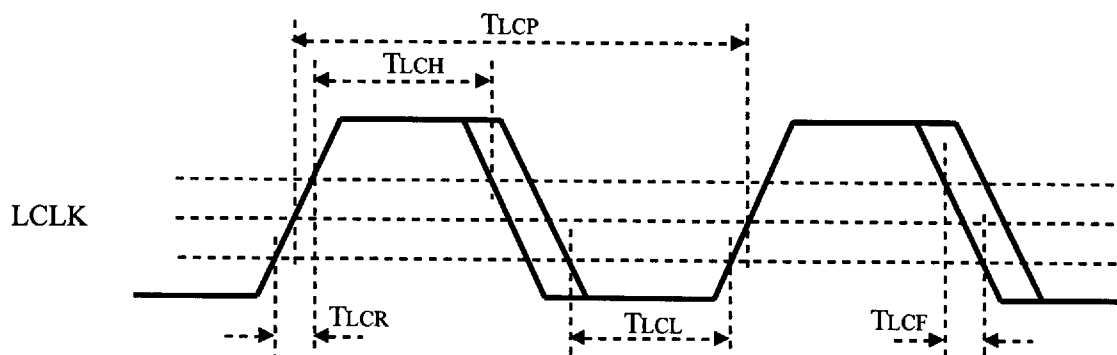
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65548 AC TIMING CHARACTERISTICS - LOCAL BUS CLOCK (40 MHz)

Symbol	Parameter	Notes	Min	Max	Units
T_{LCP}	Local Bus Clock Period(40MHz)†	0.1% stability at 2.0V / 0.8V	25	25	nS
T_{LCH}	Local Bus Clock High Time		8	—	nS
T_{LCL}	Local Bus Clock Low Time		8	—	nS
T_{LCR}	Local Bus Clock Rise Time		—	2	nS
T_{LCF}	Local Bus Clock Fall Time		—	2	nS
—	Local Bus Clock Slew Rate		1	4	V / nS
T_{CRS}	CPU Reset Setup Time to Local Bus Clock	For 2x Clock Sync	2	—	nS
T_{CRH}	CPU Reset Hold Time from Local Bus Clock	For 2x Clock Sync	5	—	nS

Note: † VL-Bus timing is compatible with VL-Bus Specification 2.0. 50 MHz VL-Bus operation assumes BVCC and IVCC both at 5V. VL-Bus operation at 3.3V is limited to 40 MHz (refer to the VL-Bus 2.0 specification for 33 MHz timing details).

Note: The typical input capacitance on LCLK is 10pF.

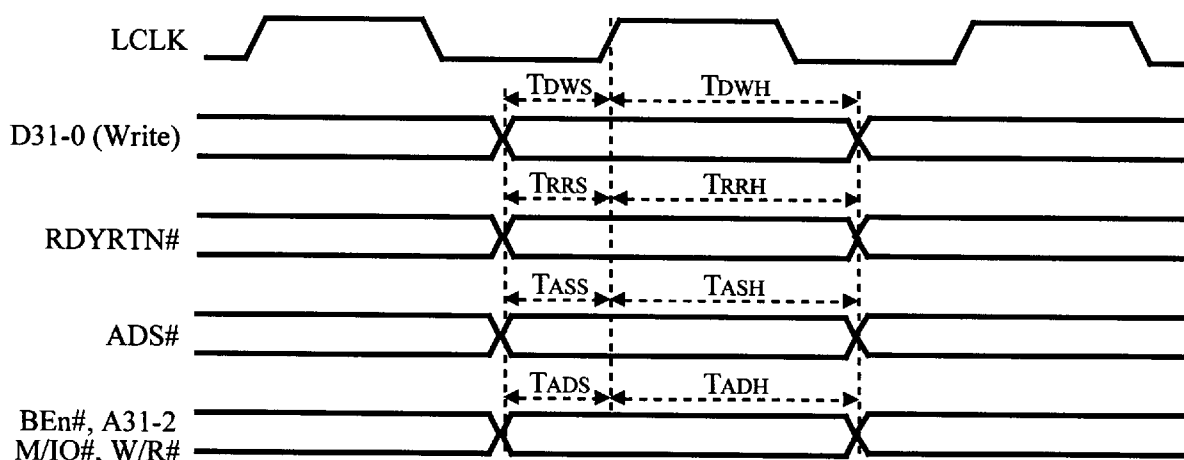


Local Bus Clock Timing

Note: Unless otherwise specified, specifications above apply to both 5V & 3.3V operation & memory clock is assumed to be 75MHz. Electrical specifications contained herein are preliminary and subject to change without notice.

65548 AC TIMING CHARACTERISTICS - LOCAL BUS INPUT SETUP & HOLD (40 MHz)

Symbol	Parameter	Notes	Min	Max	Units
T_{ADS}	Setup Time - A2-31,BEn#,M/IO#,W/R#		6	—	nS
T_{ASS}	Setup Time - ADS#		6	—	nS
T_{DWS}	Setup Time - D0-31 (Write)		6	—	nS
T_{RRS}	Setup Time - RDYRTN#		5	—	nS
T_{ADH}	Hold Time - A2-31,BEn#,M/IO#,W/R#		2	—	nS
T_{ASH}	Hold Time - ADS#		2	—	nS
T_{DWH}	Hold Time - D0-31 (Write)		2	—	nS
T_{RRH}	Hold Time - RDYRTN#		2	—	nS

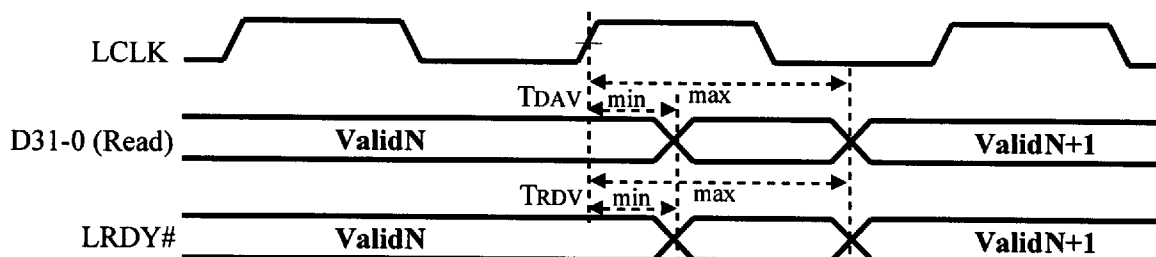


Local Bus Input Setup & Hold Timing

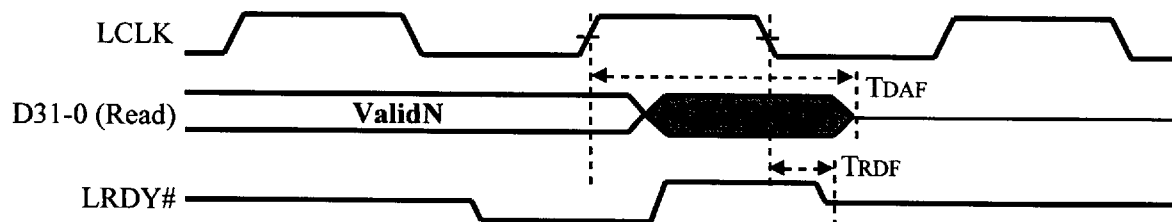
Note: Unless otherwise specified, specifications above apply to both 5V & 3.3V operation & memory clock is assumed to be 75MHz. Electrical specifications contained herein are preliminary and subject to change without notice.

65548 AC TIMING CHARACTERISTICS - LOCAL BUS OUTPUT VALID (40 MHz)

Symbol	Parameter	Notes	Min	Max	Units
T_{DAV}	Bus Clock to Output Valid - D0-31 (Read)		3	14	nS
T_{RDV}	Bus Clock to Output Valid - LRDY#		3	13	nS


Local Bus Output Valid Timing
65548 AC TIMING CHARACTERISTICS - LOCAL BUS FLOAT DELAY (40 MHz)

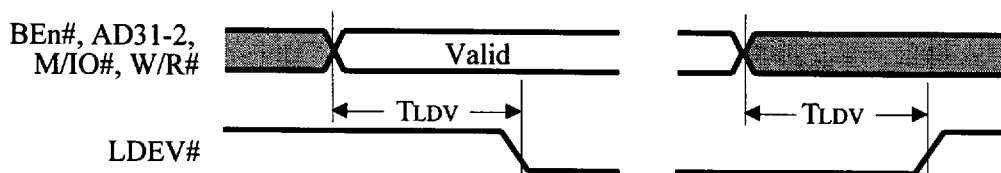
Symbol	Parameter	Notes	Min	Max	Units
T_{DAF}	Float Delay - D0-31 (Read)		—	18	nS
T_{RDF}	Float Delay - LRDY#	Driven high before floating	—	15	nS


Local Bus Output Float Delay Timing

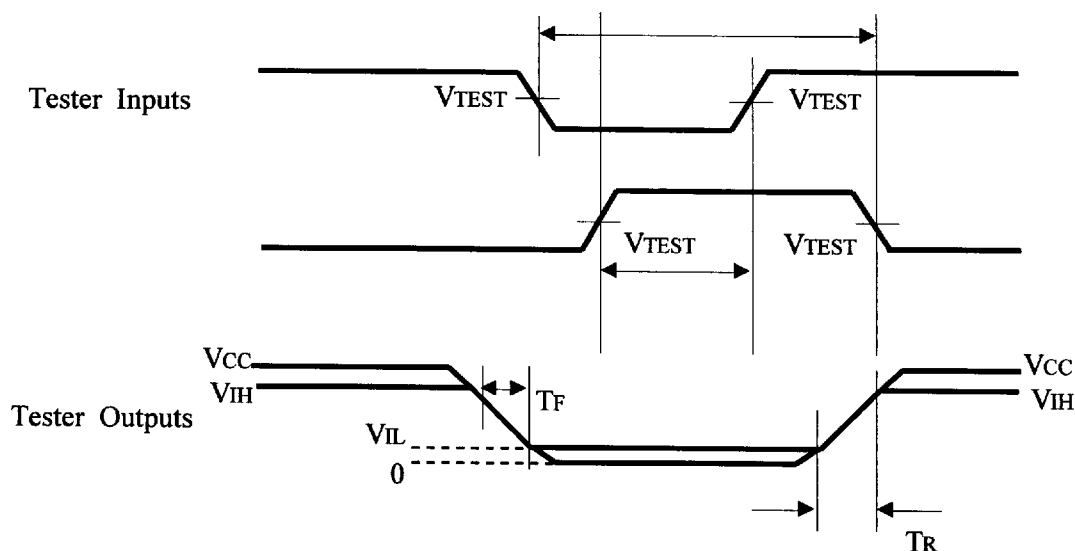
Note: Unless otherwise specified, specifications above apply to both 5V & 3.3V operation & memory clock is assumed to be 75MHz.
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65548 AC TIMING CHARACTERISTICS - VL BUS LDEV# (40 MHz)

Symbol	Parameter	Notes	Min	Typ	Max	Units
T_{LDV}	Address to LDEV# change		3	–	20	nS


VL-Bus LDEV# Timing
65548 AC TEST CONDITIONS

Symbol	Notes	3.3 Volt Signaling	5 Volt Signaling	Units
V_{CC}	Supply Voltage	3.1	5.5	V
V_{TEST}	All AC parameters	$0.4 V_{CC}$	1.5	V
V_{IL}	Input low voltage (10% of V_{CC})	$0.1 V_{CC}$ (Min)	–	V
V_{IH}	Input high voltage (90% of V_{CC})	–	$0.9 V_{CC}$ (Max)	V
T_R	Maximum input rise time (3/5.5V)	3	3	nS
T_F	Maximum input fall time (3/5.5V)	2	2	nS

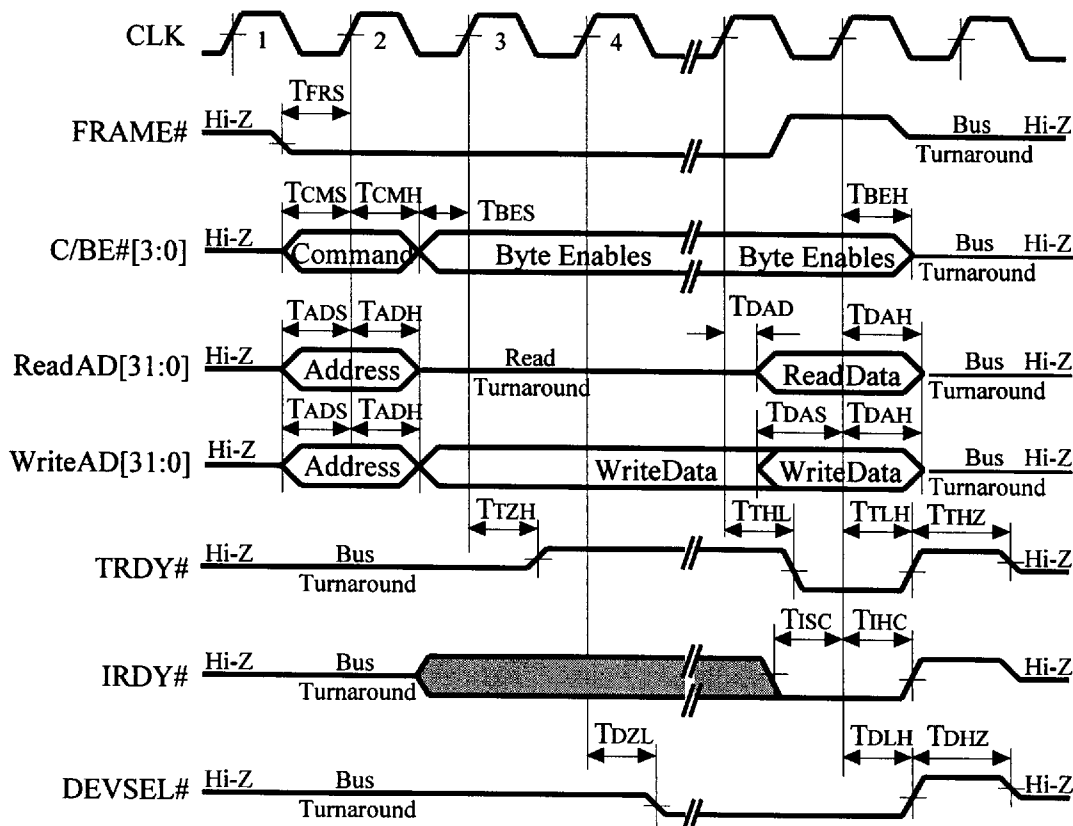

AC Test Timing

Note: Unless otherwise specified, specifications above apply to both 5V & 3.3V operation & memory clock is assumed to be 75MHz.
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65548 AC TIMING CHARACTERISTICS - PCI BUS FRAME (33 MHz)

Symbol	Parameter	Notes	Min	Max	Units
T _{FRS}	FRAME# Setup to CLK		7	—	nS
T _{CMS}	C/BE#[3:0] (Bus CMD) Setup to CLK		7	—	nS
T _{CMH}	C/BE#[31:0] (Bus CMD) Hold from CLK		2	—	nS
T _{BES}	C/BE#[3:0] (Byte Enable) Setup to CLK		7	—	nS
T _{BEH}	C/BE#[3:0] (Byte Enable) Hold from CLK		2	—	nS
T _{ADS}	AD[31:0] (Address) Setup to CLK		7	—	nS
T _{ADH}	AD[31:0] (Address) Hold from CLK		2	—	nS
T _{DAS}	AD[31:0] (Data) Setup to CLK		7	—	nS
T _{DAH}	AD[31:0] (Data) Hold from CLK		2	—	nS
T _{DAD}	AD[31:0] (Data) Valid from CLK		—	11	nS
T _{TZH}	TRDY# High Z to High from CLK		—	11	nS
T _{THL}	TRDY# Active from CLK		—	11	nS
T _{TLH}	TRDY# Inactive from CLK		2	11	nS
T _{THZ}	TRDY# High before High Z		1	1	CLK
T _{DZL}	DEVSEL# Active from CLK		—	11	nS
T _{DLH}	DEVSEL# Inactive from CLK		2	11	nS
T _{DHZ}	DEVSEL# High before High Z		1	1	CLK
T _{ISC}	IRDY# Setup to CLK		7	—	nS
T _{IHC}	IRDY# Hold from CLK		2	—	nS

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PCI Bus Frame Timing

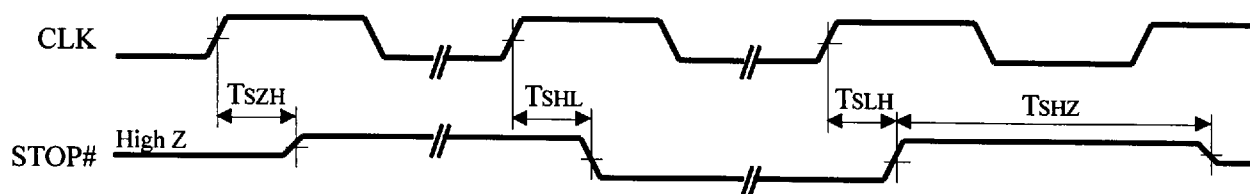
Note: The above diagram shows a typical PCI bus cycle. PCI bus read cycles require a bus turn-around cycle between address output and data input on AD31:0. PCI bus write cycles do not require this bus turn-around cycle so the write data is available from the bus master immediately after address output (in clock cycle 2 instead of clock cycle 3).

Note: Only consecutive active byte enables [BE(3:0)] are supported for both memory and I/O accesses.

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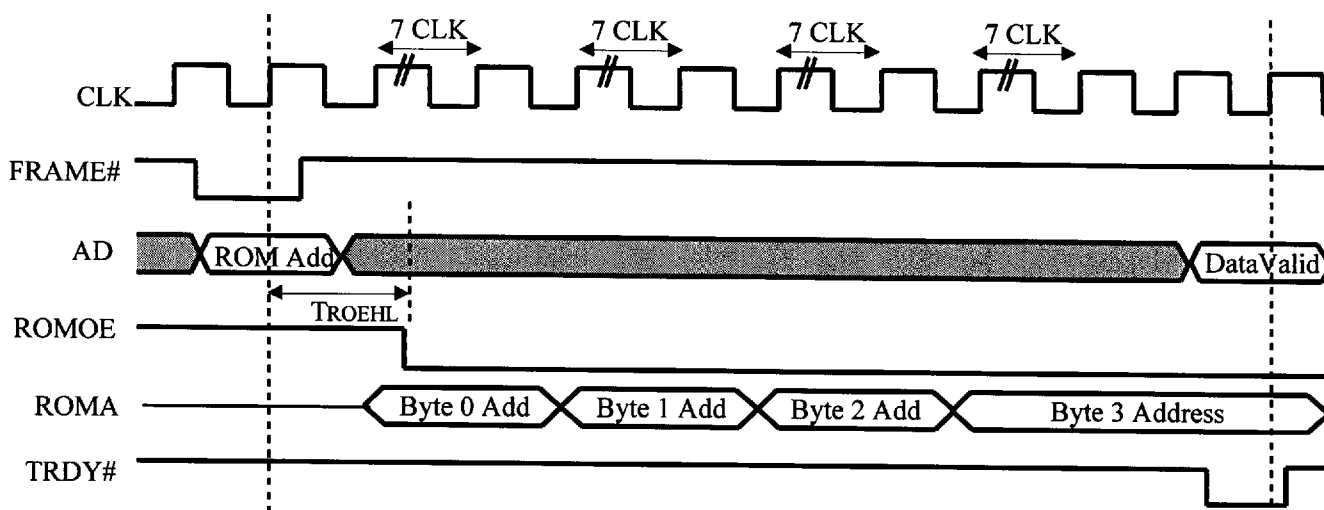
65548 AC TIMING CHARACTERISTICS - PCI BUS STOP (33 MHz)

Symbol	Parameter	Notes	Min	Max	Units
T _{SZH}	STOP# High Z to High from CLK		—	11	nS
T _{SHL}	STOP# Active from CLK		—	11	nS
T _{SLH}	STOP# Inactive from CLK		—	11	nS
T _{SHZ}	STOP# High before High Z		1	1	CLK


PCI Bus Stop Timing
65548 AC TIMING CHARACTERISTICS - PCI BIOS ROM

Symbol	Parameter	Notes	Min	Max	Units
T _{ROE}	ROMOE# Active from CLK		—	40	nS

Note: PCI BIOS ROM timing is derived from the PCI bus clock. Timing sequences are fixed assuming the use of widely-available, low-cost, typical industry-standard EPROMs. Timing specifications and performance of BIOS ROM memory accesses are non-critical since PCI BIOS ROM data is always shadowed into high-speed system memory prior to execution of BIOS code.

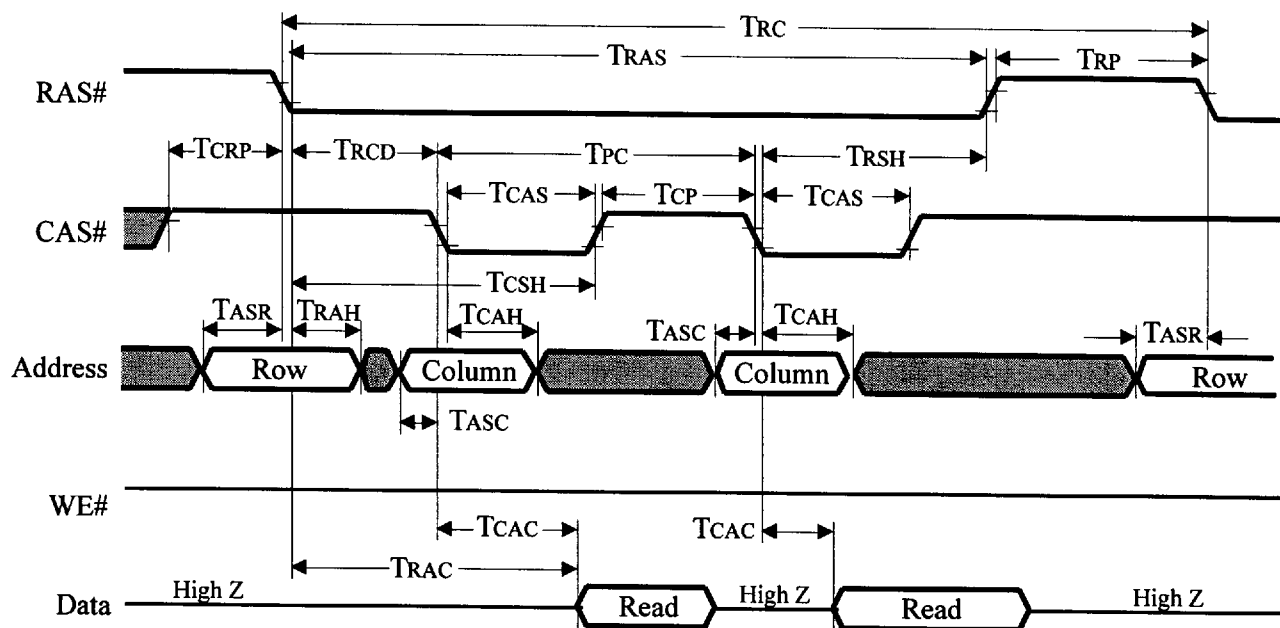
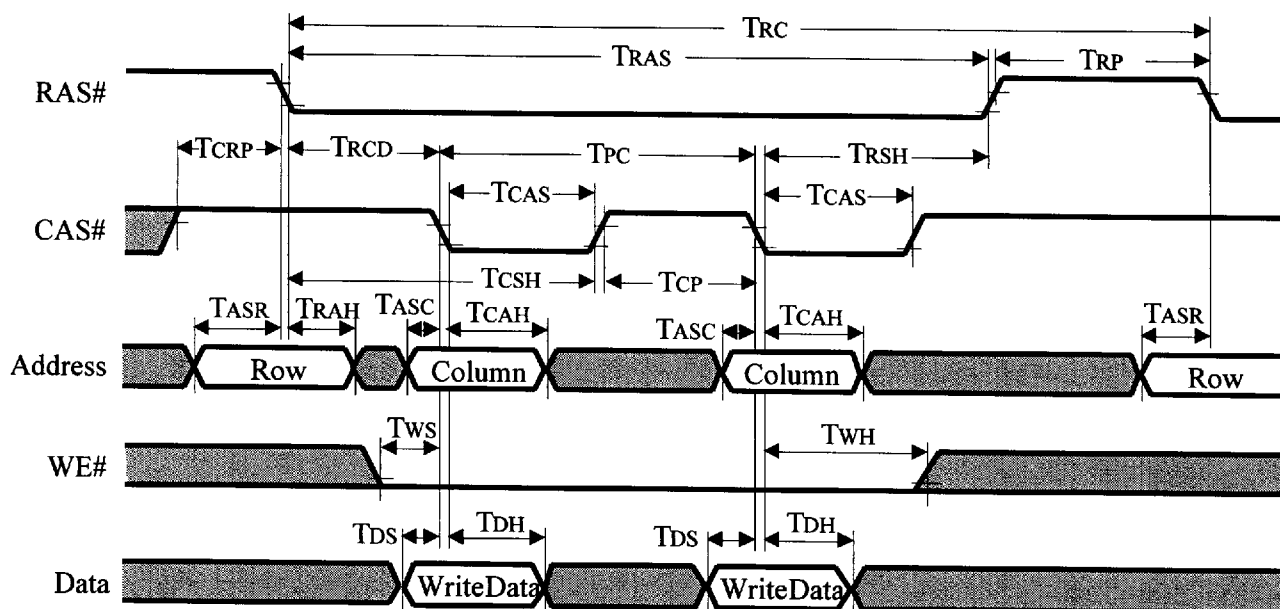

PCI BIOS ROM Timing

Note: Unless otherwise specified, specifications above apply to both 5V & 3.3V operation & memory clock is assumed to be 75MHz. Electrical specifications contained herein are preliminary and subject to change without notice.

65548 AC TIMING CHARACTERISTICS - DRAM READ/WRITE

Symbol	Parameter	Notes	Min	Max	Units
T_{RC}	Read/Write Cycle Time	$T_{RCD}=3, T_{RP}=3$ (Reset)	$11T_m - 2$	—	nS
		$T_{RCD}=3, T_{RP}=4$ (Normal)	$12T_m - 2$	—	nS
		$T_{RCD}=4, T_{RP}=3$	$12T_m - 2$	—	nS
		$T_{RCD}=4, T_{RP}=4$	$13T_m - 2$	—	nS
T_{RAS}	RAS# Pulse Width	XR05[3]=0 ($T_{RCD}=3$ Clks) (Default)	$8T_m - 2$	—	nS
		XR05[3]=1 ($T_{RCD}=4$ Clks)	$9T_m - 2$	—	nS
T_{RP}	RAS# Precharge	XR04[4]=0 ($T_{RP}=3$ Clks)	$3T_m - 3$	—	nS
T_{CRP}	CAS# to RAS# Precharge	XR04[4]=1 ($T_{RP}=4$ Clks) (Default)	$4T_m - 3$	—	nS
		XR04[4]=1 ($T_{RP}=4$ Clks) (Default)	$4T_m - 5$	—	nS
		XR04[4]=0 ($T_{RP}=3$ Clks)	$3T_m - 5$	—	nS
T_{CSH}	CAS# Hold from RAS#	XR05[3]=0 ($T_{RCD}=3$ Clks) (Default)	$5T_m - 2$	—	nS
		XR05[3]=1 ($T_{RCD}=4$ Clks), (4Clk CAS)	$6T_m - 2$	—	nS
T_{RCD}	RAS# to CAS# Delay	XR05[3]=0 ($T_{RCD}=3$ Clks) (Default)	$3T_m - 5$	—	nS
		XR05[3]=1 ($T_{RCD}=4$ Clks)	$4T_m - 5$	—	nS
T_{RSH}	RAS# Hold from CAS#		$2T_m - 5$	—	nS
T_{CP}	CAS# Precharge		$T_m - 2$	—	nS
T_{CAS}	CAS# Pulse Width		$2T_m - 5$	—	nS
T_{ASR}	Row Address Setup to RAS#		$T_m - 8$	—	nS
T_{ASC}	Column Address Setup to CAS#		$2T_m - 9$	—	nS
T_{RAH}	Row Address Hold from RAS#		$T_m - 2$	—	nS
T_{CAH}	Column Address Hold from CAS#		$T_m - 2$	—	nS
T_{CAC}	Data Access Time from CAS#	XR05[2-1]=0 (3Clk CAS) Std	—	$2T_m - 5$	nS
		XR05[2-1]=0 (3Clk CAS) EDO	—	$2.5T_m - 5$	nS
		XR05[2-1]=1 (4Clk CAS) Std	—	$3T_m - 5$	nS
		XR05[2-1]=1 (4Clk CAS) EDO	—	$3.5T_m - 5$	nS
T_{RAC}	Data Access Time from RAS#	XR05[2-1]=0 ($T_{RCD}=3$ Clks) Std	—	$5T_m - 2$	nS
		XR05[2-1]=0 ($T_{RCD}=3$ Clks) EDO	—	$5.5T_m - 2$	nS
		XR05[2-1]=1 ($T_{RCD}=3$ Clks) Std	—	$6T_m - 2$	nS
		XR05[2-1]=1 ($T_{RCD}=3$ Clks) EDO	—	$6.5T_m - 2$	nS
		XR05[2-1]=0 ($T_{RCD}=4$ Clks) Std	—	$6T_m - 2$	nS
		XR05[2-1]=0 ($T_{RCD}=4$ Clks) EDO	—	$6.5T_m - 2$	nS
		XR05[2-1]=1 ($T_{RCD}=4$ Clks) Std	—	$7T_m - 2$	nS
		XR05[2-1]=1 ($T_{RCD}=4$ Clks) EDO	—	$7.5T_m - 2$	nS
T_{DS}	Write Data Setup to CAS#	XR05[3]=0 ($T_{RCD}=3$ Clks) (Default)	$T_m - 9$	—	nS
		XR05[3]=1 ($T_{RCD}=4$ Clks)	$2T_m - 9$	—	nS
T_{DH}	Write Data Hold from CAS#		$T_m - 2$	—	nS
T_{PC}	CAS Cycle Time		$3T_m - 1$	—	nS
T_{WS}	WE# Setup to CAS#	XR05[3]=0 ($T_{RCD}=3$ Clks) (Default)	$T_m - 5$	—	nS
		XR05[3]=1 ($T_{RCD}=4$ Clks)	$2T_m - 5$	—	nS
T_{WP}	WE# Hold from CAS#		$2T_m - 5$	—	nS

Note: The minimum T_{RAS} is 8 clocks for a 2 CAS page mode cycle. Without page mode it is 5 clocks.

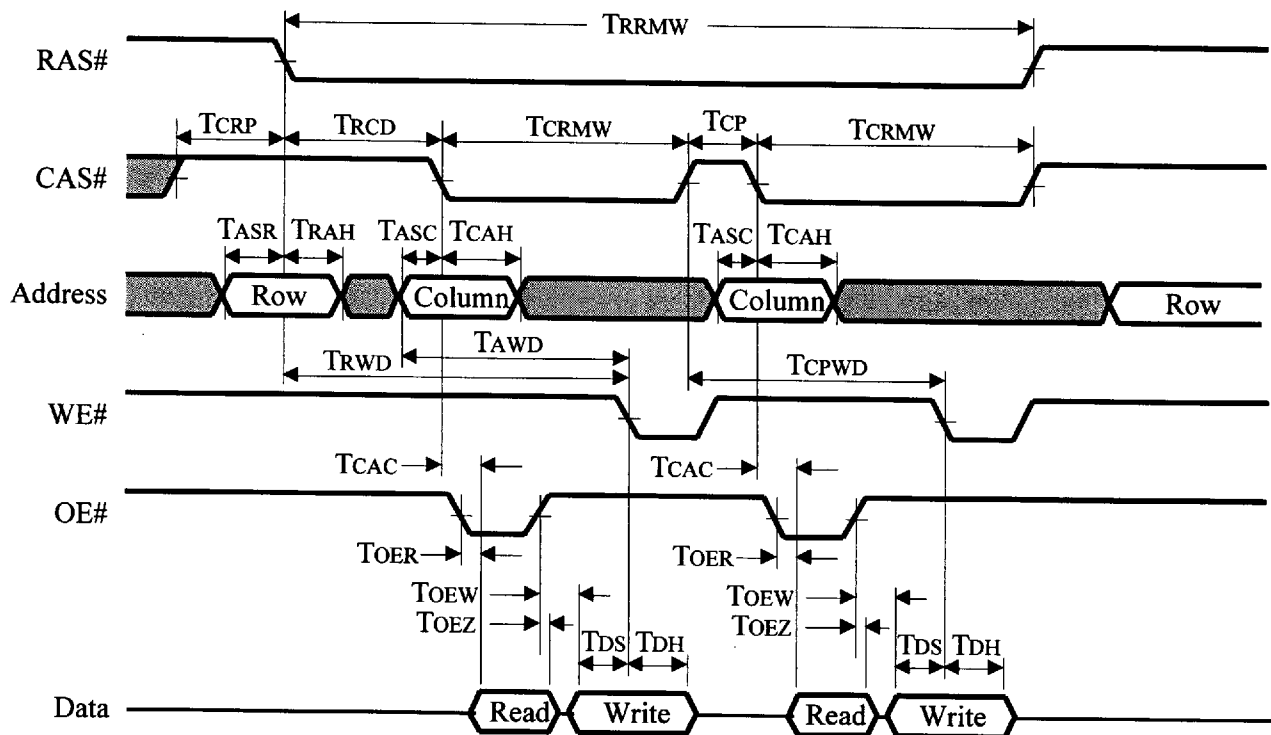

DRAM Page Mode Read Cycle Timing

DRAM Page Mode Write Cycle Timing

Note: The above diagrams represent typical page mode cycles. The number of actual CAS cycles may vary.

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65548 AC TIMING CHARACTERISTICS - DRAM READ/MODIFY/WRITE

Symbol	Parameter	Notes	Min	Max	Units
T_{RRMW}	RAS# Pulse Width	XR05[3]=0 ($T_{RCD}=3$ Clks) (Default)	$16T_m - 5$	—	nS
		XR05[3]=1 ($T_{RCD}=4$ Clks)	$17T_m - 5$	—	nS
T_{CRMW}	CAS# Pulse Width		$6T_m - 5$	—	nS
T_{AWD}	Col Address to WE# Delay	XR05[3]=0 ($T_{RCD}=3$ Clks) (Default)	$6T_m - 8$	—	nS
		XR05[3]=1 ($T_{RCD}=4$ Clks)	$7T_m - 8$	—	nS
T_{RWD}	RAS# to WE# Delay	XR05[3]=0 ($T_{RCD}=3$ Clks) (Default)	$7T_m - 5$	—	nS
		XR05[3]=1 ($T_{RCD}=4$ Clks)	$8T_m - 5$	—	nS
T_{CPWD}	CAS# Precharge to WE# Delay		$5T_m - 5$	—	nS
T_{OEZ}	Output Turnoff Delay from OE#		—	T_m	nS
T_{OEW}	OE# Write Data Delay		$T_m + 3$	—	nS
T_{OER}	OE# Read Data Delay	XR05[7]=0 (Std DRAMS)	—	$2T_m - 5$	nS
		XR05[7]=1 (EDO DRAMs)	—	$3T_m - 5$	nS
		XR05[1]=1 (4 Clk CAS)	—	$3T_m - 5$	nS

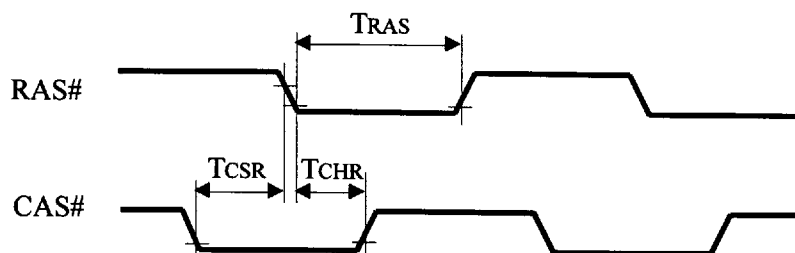

DRAM Page Mode Read Modify Write Cycle Timing

Note: The above diagrams represent typical page mode cycles. The number of actual CAS cycles may vary.

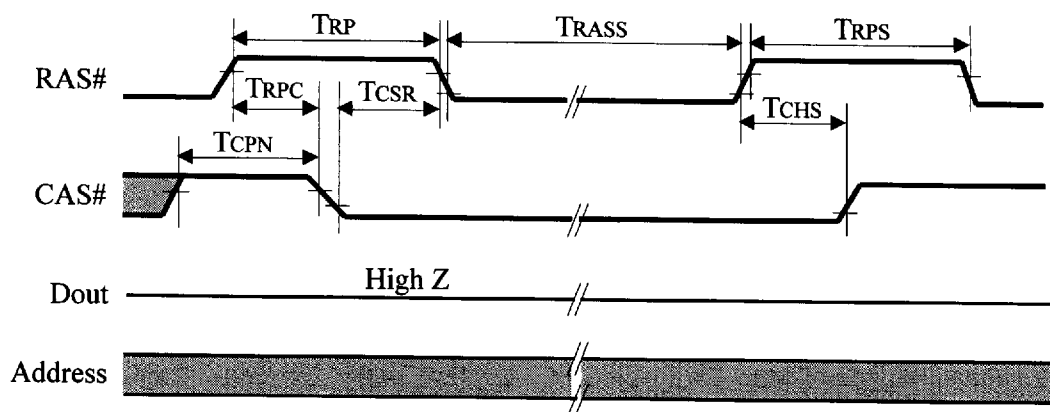
Note: Unless otherwise specified, specifications above apply to both 5V & 3.3V operation & memory clock is assumed to be 75MHz. Electrical specifications contained herein are preliminary and subject to change without notice.

65548 AC TIMING CHARACTERISTICS - CBR REFRESH

Symbol	Parameter	Notes	Min	Typ	Max	Units
T_{CHR}	RAS# to CAS# Delay		$5T_m - 5$	—	—	nS
T_{CSR}	CAS# to RAS# Delay	Normal Operation	$T_m - 2$	—	—	nS
		Standby Mode	$2T_m - 5$	—	—	nS
T_{RAS}	RAS# Pulse Width		$5T_m - 5$	—	—	nS


CAS-Before-RAS (CBR) DRAM Refresh Cycle Timing
65548 AC TIMING CHARACTERISTICS - SELF REFRESH

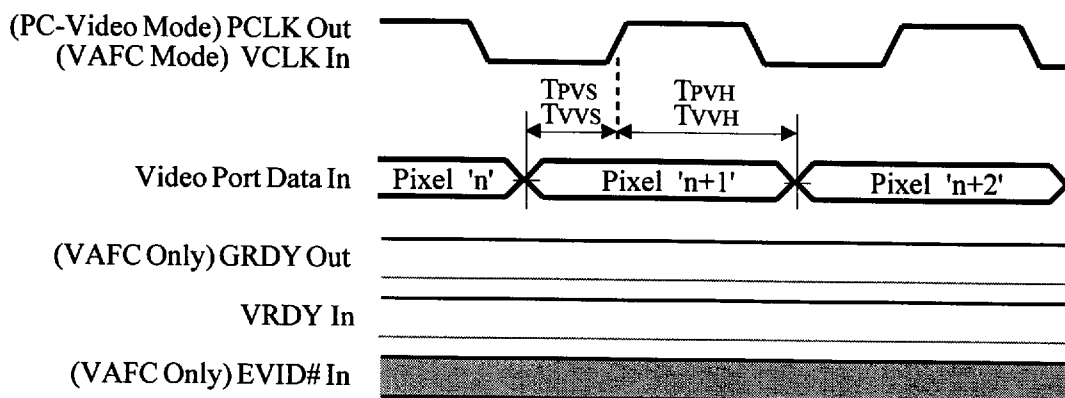
Symbol	Parameter	Notes	Min	Typ	Max	Units
T_{RASS}	RAS# Pulse Width for Self-Refresh		100	—	—	μ S
T_{RP}	RAS# Precharge	XR04[4]=0 (T_{RP} =3 Clks)	$3T_m - 3$	—	—	nS
		XR04[4]=1 (T_{RP} =4 Clks) (Default)	$4T_m - 3$	—	—	nS
T_{RPS}	RAS# Precharge for Self-Refresh		$10T_m$	—	—	nS
T_{RPC}	RAS# to CAS# Delay		$3T_m - 5$	—	—	nS
T_{CSR}	CAS# to RAS# Delay	Normal Operation	$T_m - 2$	—	—	nS
		Standby Mode	$2T_m - 5$	—	—	nS
T_{CHS}	CAS# Hold Time		0	—	—	nS
T_{CPN}	CAS# Precharge		$T_m - 5$	—	—	nS


'Self-Refresh DRAM' Refresh Cycle Timing

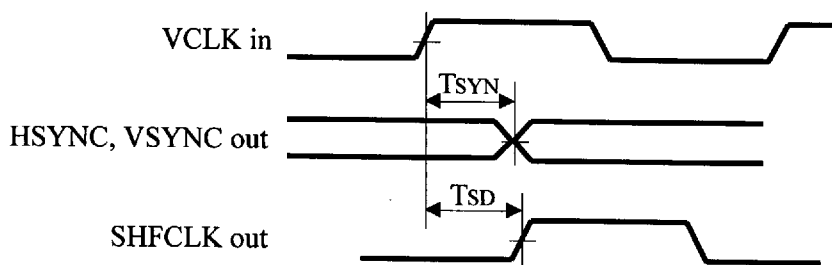
Note: Upon exiting self-refresh mode, the 65548 will perform a complete set of CBR refresh cycles before resuming normal DRAM activity. The duration of the burst refresh will equal the panel power sequencing delay, programmed in XR5B bits 7-4.

65548 AC TIMING CHARACTERISTICS - VIDEO INPUT PORT TIMING

Symbol	Parameter	Notes	Min	Max	Units
T_{PVS}	Video Port Input Data Setup to PCLK out	PC-Video Mode	12	–	nS
T_{PVH}	Video Port Input Data Hold from PCLK out	PC-Video Mode	0	–	nS
T_{VVS}	Video Port Input Data Setup to VCLK in	VAFC Mode	10	–	nS
T_{PVH}	Video Port Input Data Hold from VCLK in	VAFC Mode	2	–	nS
T_{VCK}	VCLK Input Frequency	VAFC 1.0 Specification	–	37.5	MHz
T_{VCH}	VCLK Input Clock High Time	VAFC 1.0 Specification	10	–	nS
T_{VCL}	VCLK Input Clock Low Time	VAFC 1.0 Specification	10	–	nS


Video Input Port Timing
65548 AC TIMING CHARACTERISTICS - CRT OUTPUT TIMING

Symbol	Parameter	Notes	Min	Max	Units
T_{SYN}	HSYNC, VSYNC delay from VCLK in		–	50	nS
T_{SYN}	HSYNC, VSYNC delay from VCLK in (3.3V)		–	80	nS
T_{SD}	VCLK in to SHFCLK delay		–	30	nS
T_{SD}	VCLK in to SHFCLK delay (3.3V)		–	50	nS

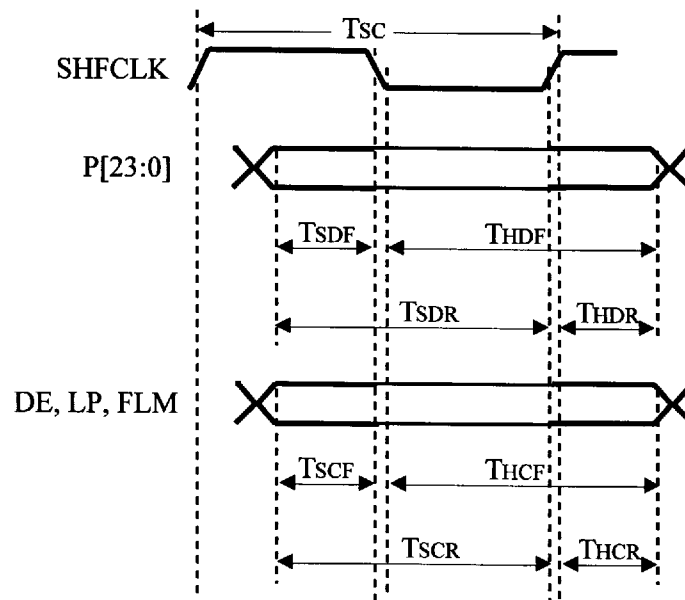

CRT Output Timing

Note: Unless otherwise specified, specifications above apply to both 5V & 3.3V operation & memory clock is assumed to be 75MHz.
Electrical specifications contained herein are preliminary and subject to change without notice.

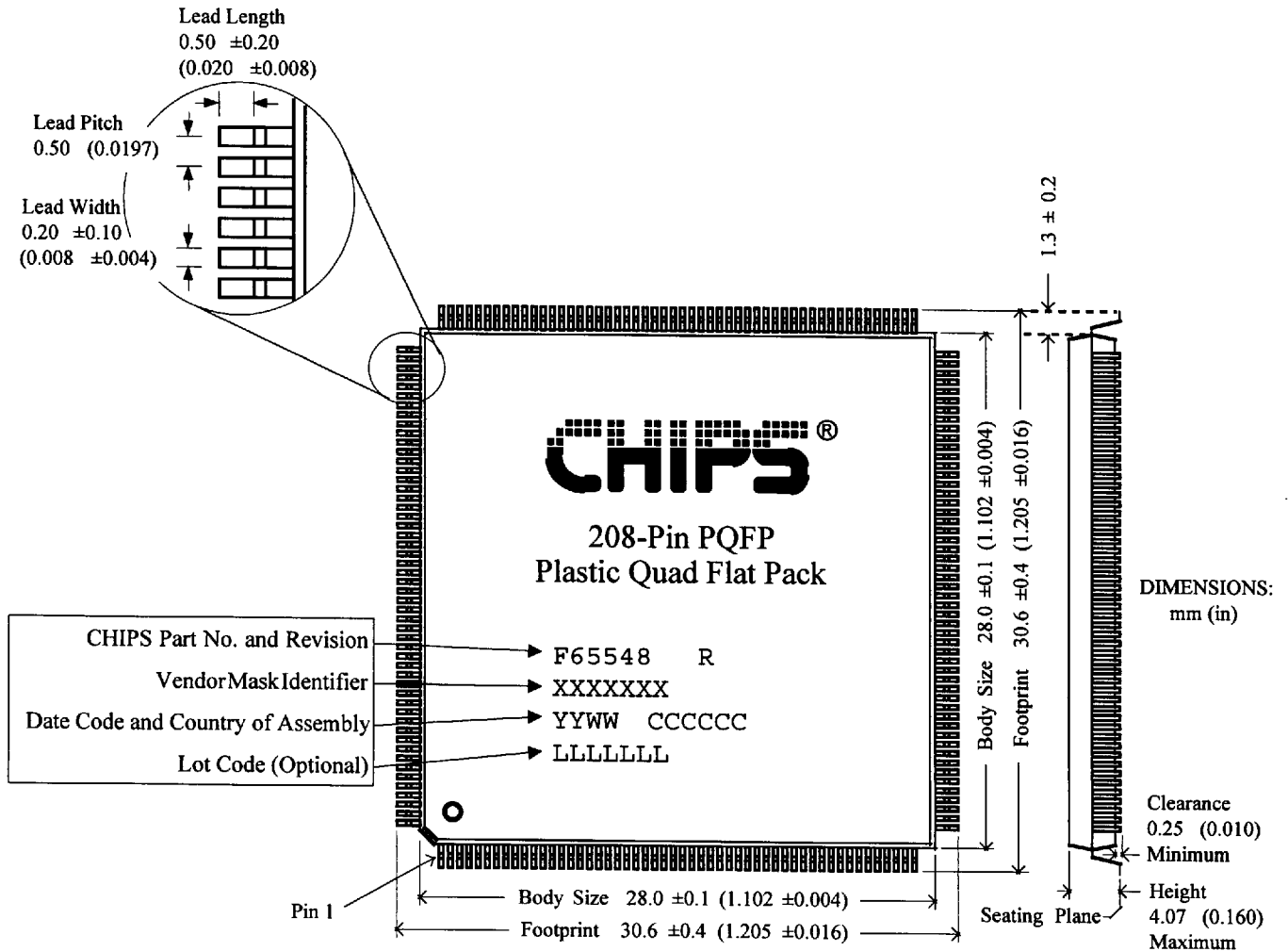
65548 AC TIMING CHARACTERISTICS - PANEL OUTPUT TIMING

Symbol	Parameter	Notes	Min	Max	Units
T_{SC}	SHFCLK cycle time	Data latched on SHFCLK fall	25	—	nS
		Data latched on SHFCLK rise	15	—	nS
T_{SDF}	Panel data setup to SHFCLK fall		$1/2 T_{SC}-5$	—	nS
T_{HDF}	Panel data hold to SHFCLK fall		$1/2 T_{SC}-3$	—	nS
T_{SDR}	Panel data setup to SHFCLK rise		$T_{SC}-10$	—	nS
T_{HDR}	Panel data hold to SHFCLK rise		0	—	nS
T_{SCF}	Panel control setup to SHFCLK fall		$1/2 T_{SC}-5$	—	nS
T_{HCF}	Panel control hold to SHFCLK fall		$1/2 T_{SC}-3$	—	nS
T_{SCR}	Panel control setup to SHFCLK rise		$T_{SC}-10$	—	nS
T_{HCR}	Panel control hold to SHFCLK rise		-3	—	nS

Note: AC Timing is valid when: DVCC=5V, XR6C[2]=X, max output loading=50pF or when: DVCC=3.3V, XR6C[2]=1, max output loading=25pF.


Panel Output Timing

Mechanical Specifications Plastic Quad Flat Pack (PQFP)



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